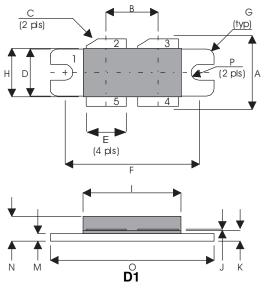


METAL GATE RF SILICON FET

MECHANICAL DATA



PIN 1 SOURCE (COMMON) PIN₃ DRAIN 2

PIN₂ DRAIN 1 PIN 4 GATE 2

GATE 1 PIN 5

DIM	Millimetres	Tol.	Inches	Tol.
Α	15.24	0.50	0.600	0.020
В	10.80	0.13	0.425	0.005
С	45°	5°	45°	5°
D	9.78	0.13	0.385	0.005
Е	8.38	0.13	0.330	0.005
F	27.94	0.13	1.100	0.005
G	1.52R	0.13	0.060R	0.005
Н	10.16	0.15	0.400	0.006
- 1	21.84	0.23	0.860	0.009
J	0.10	0.02	0.004	0.001
K	1.96	0.13	0.077	0.005
М	1.02	0.13	0.040	0.005
N	4.45	0.38	0.175	0.015
0	34.04	0.13	1.340	0.005
Р	1.63R	0.13	0.064R	0.005

GOLD METALLISED MULTI-PURPOSE SILICON DMOS RF FET 350W - 28V - 175MHz**PUSH-PULL**

FEATURES

- SUITABLE FOR BROAD BAND APPLICATIONS
- SIMPLE BIAS CIRCUITS
- ULTRA-LOW THERMAL RESISTANCE
- BeO FREE
- LOW Crss
- HIGH GAIN 16 dB MINIMUM

APPLICATIONS

 VHF/UHF COMMUNICATIONS from 1 MHz to 400 MHz

ABSOLUTE MAXIMUM RATINGS (T_{case} = 25 °C unless otherwise stated)

$\overline{P_D}$	Power Dissipation	875W (438W -A Version)
BV_DSS	Drain – Source Breakdown Voltage *	70V
BV_{GSS}	Gate – Source Breakdown Voltage*	±20V
I _{D(sat)}	Drain Current*	35A
T _{stg}	Storage Temperature	−65 to 150°C
T _j	Maximum Operating Junction Temperature	200°C

Per Side

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Website: http://www.semelab.co.uk E-mail: sales@semelab.co.uk



ELECTRICAL CHARACTERISTICS ($T_{case} = 25$ °C unless otherwise stated)

Parameter		Test Conditions		Min.	Тур.	Max.	Unit
	PER SIDE						
BV _{DSS}	Drain–Source Breakdown Voltage	V _{GS} = 0	I _D = 100mA	70			V
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 28V	V _{GS} = 0			7	mA
I _{GSS}	Gate Leakage Current	V _{GS} = 20V	$V_{DS} = 0$			7	μА
V _{GS(th)}	Gate Threshold Voltage*	I _D = 10mA	$V_{DS} = V_{GS}$	1		7	V
9 _{fs}	Forward Transconductance*	V _{DS} = 10V	I _D = 6A	5.6			mhos
V _{GS(th)m}	Gate Threshold Voltage atch Matching Between Sides	I _D = 10mA	V _{DS} = V _{GS}			0.1	V
		TOTAL	DEVICE				•
G _{PS}	Common Source Power Gain	P _O = 350W		16			dB
η	Drain Efficiency	V _{DS} = 28V	I _{DQ} = 2A	60			%
VSWR	Load Mismatch Tolerance	f = 175MHz		20:1			_
PER SIDE							
C _{iss}	Input Capacitance	$V_{DS} = 28V V_{G}$	S = -5V $f = 1MHz$			420	pF
C _{oss}	Output Capacitance	$V_{DS} = 28V V_{G}$	S = 0 f = 1MHz			210	pF
C _{rss}	Reverse Transfer Capacitance	$V_{DS} = 28V V_{G}$	S = 0 f = 1MHz			17.5	pF

Pulse Duration = 300 μs , Duty Cycle ≤ 2% * Pulse Test:

THERMAL DATA

R _{THj-case}	Thermal Resistance Junction – Case	Max. 0.2°C/W
,		0.4 °C / W -A Version

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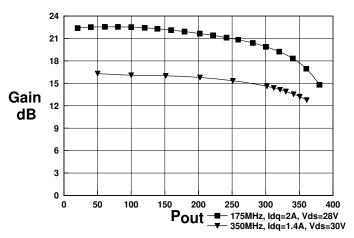


Figure 1 – Gain vs. Power Output.

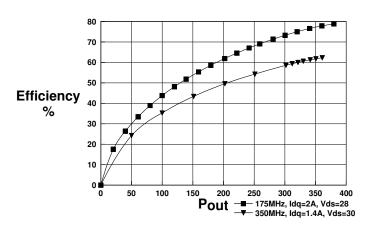


Figure 2 – Efficiency vs. Power Output.

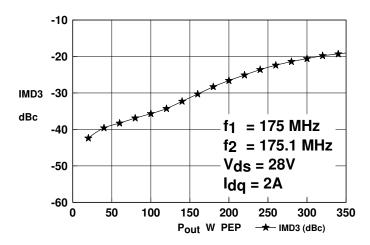


Figure 3 - IMD vs. Power Output

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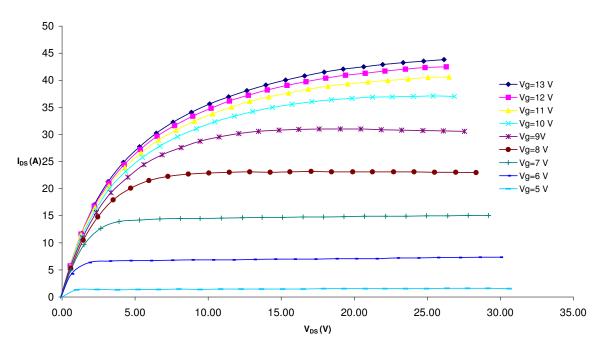


Figure 4 – Typical IV Characteristics.

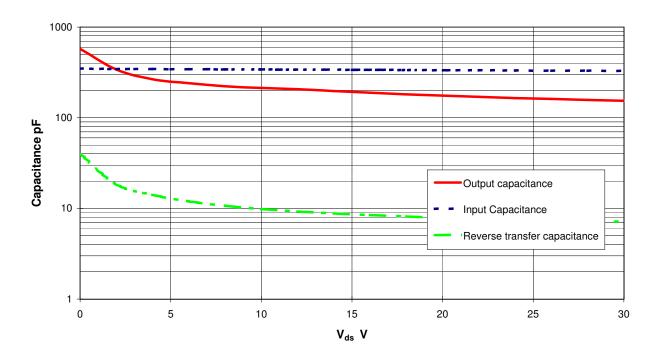


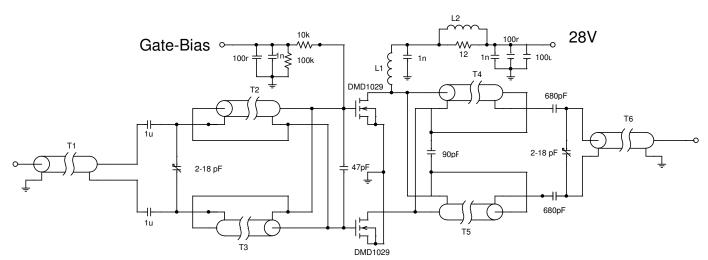
Figure 5 – Typical CV Characteristics.

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DMD1029 175MHz TEST JIG

- 2 hole core 2 hole core 7cm RG316 coax on Siemens A1 x 1
- T2,3 7cm RG316 coax on Siemens A1 x 1
- T4,5 14cm RG316 coax
- 11cm RG316 coax
- 1.5 turns 1mm dia wire on Siemens A1 x 1 2 hole core
- 8.5 turns 1mm dia wire, 4mm internal diameter

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